Docket No.	

COMBINED DECLARATION/POWER OF ATTORNEY FOR PATENT APPLICATION

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name. I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled POLISHING METHOD FOR SEMICONDUCTOR DEVICE, METHOD FOR FABRICATING SEMICONDUCTOR DEVICE, AND POLISHING SYSTEM, the specification of which (check one) is attached hereto. X was filed on Application Serial No. I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above. I acknowledge the duty to disclose information which is material to the examination of this application in accordance with Title 37, Code of Federal Regulations, § 1.56(a). I hereby claim foreign priority benefits under Title 35, United States Code, § 119 of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed: Prior Foreign Application(s) Priority Claimed 2002-373582 **JAPAN** 25/12/2002 X Yes No (Number) (Country) (Day/Month/Year Filed) ___ Yes ___ No (Number) (Country) (Day/Month/Year Filed) ___ Yes ___ No (Number) (Country) (Day/Month/Year Filed)

I hereby claim the benefit under Title 35, United States Code, § 120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, § 112, I acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, § 1.56(a) which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

(Appln. Serial No.)	(Filing Date)	(Status-patented, pending, abandoned)
(Appln. Serial No.)	(Filing Date)	(Status-patented, pending, abandoned)
prosecute the patent app and Trademark Office c Jr. (Reg. No. 28,149); 28,562); Paul Devinsky E. Fogarty (Reg. No. 36	olication identified above onnected therewith: Ra Kenneth L. Cage (Reg (Reg. No. 28,553); Edw	full power of substitution and revocation to e and to transact all business in the U.S. Patentphael V. Lupo (Reg. No. 28,363); Jack Q. Lever P. No. 26,151); Stanislaus Aksman (Reg. No. ard E. Kubasiewicz (Reg. No. 30,020), Michael on (Reg. No. 36,801); Robert W. Zelnick (Reg. 37,136).
Please address all corres	spondence and telephone	calls to:
	Jack Q. Lever, Jr. McDERMOTT, WILL 600 Thirteenth Street, Washington, D.C. 20 (202) 756-8000	
instructions from National Trademark Office regard attorney and the undersi	Maeda Patent Office rding this application w gned. In the event of a	S. attorneys named herein to accept and follow as to any action to be taken in the Patent and ithout direct communication between the U.S change in the persons from whom instructions till be so notified by the undersigned.
all statements made on statements were made w punishable by fine or in	information and belief with the knowledge that value or both, un	e herein of my own knowledge are true and that are believed to be true; and further that these villful false statements and the like so made are der Section 1001 of Title 18 of the United Sates jeopardize the validity of the application or an
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